

Vortex Series Silicon Drift Detectors (SDD)

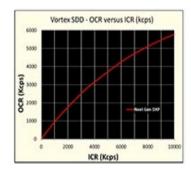


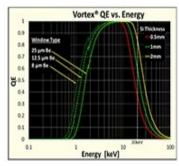


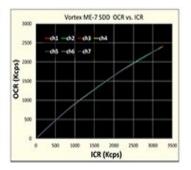
Silicon Drift Detectors for Science at the Speed of Light

Technologically Advanced Silicon Drift Detectors

- Exceptional Rise Time: < 25 ns
- Outstanding Throughput: Output count rates > 5 Mcps per channel Superior Energy Resolution: < 230 eV at 3 Mcps (OCR)
- Unique Sensor Thickness: 0.5 mm, 1.0 mm, and 2.0 mm available







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A Variety of Configurations

Sensor Thickness	0.5, 1.0, and 2.0 mm
Active Areas	50, 65, and 100 mm2
Probe Lengths	From 60 mm to over 600 mm
Sensor Arrays and Designs	Single, Multiple, Planar, Focused
Environments	Air, Vacuum, UHV, and He
Number of Sensors	Single: Vortex, Vortex-60EX, Vortex-90EX, Vortex-EM Three: Vortex-ME-3 Four: Vortex-ME-4 Seven: Vortex-ME-7

Applications

Many of the most successful research and development companies in the world trust Hitachi High-Tech equipment for the following applications:

- X-ray spectroscopy
- X-ray fluorescence measurements
- X-ray microscopy and x-ray analysis
- Synchrotron radiation applications
- Process control
- Environmental monitoring
- Spent fuel measurement and verification

Request a Quote

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